

**TC74HC373AP, TC74HC373AF, TC74HC373AFW**

**OCTAL D-TYPE LATCH WITH 3-STATE OUTPUT**

(Note) The JEDEC SOP (FW) is not available in Japan.

The TC74HC373A is a high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

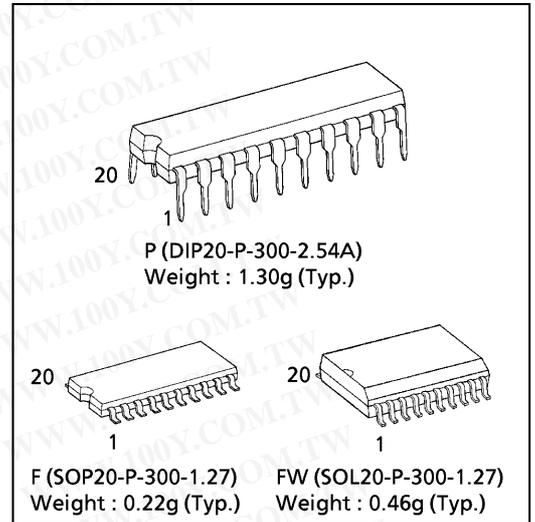
These 8-bit D-type latches are controlled by a latch enable input (LE) and a output enable input ( $\overline{OE}$ ).

When the  $\overline{OE}$  input is high, the eight outputs are in a high impedance state.

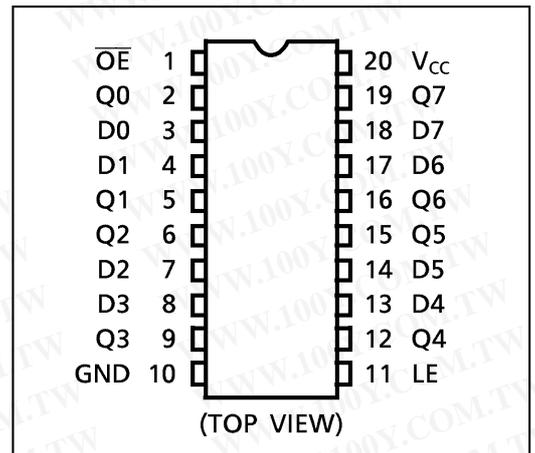
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

**FEATURES:**

- High Speed..... $t_{pd} = 11\text{ns}(\text{typ.})$  at  $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 4\mu\text{A}(\text{Max.})$  at  $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC} (\text{Min.})$
- Output Drive Capability..... 15 LSTTL Loads
- Symmetrical Output Impedance...  $|I_{OH}| = I_{OL} = 6\text{mA}(\text{Min.})$
- Balanced Propagation Delays.....  $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range...  $V_{CC} (\text{opr.}) = 2\text{V} \sim 6\text{V}$
- Pin and Function Compatible with 74LS373



**PIN ASSIGNMENT**

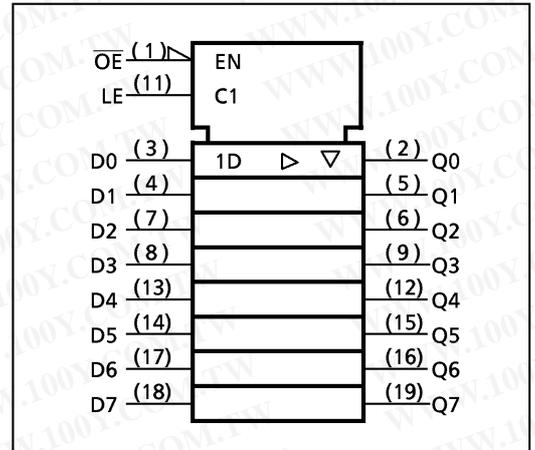


**TRUTH TABLE**

INPUTS			OUTPUTS
$\overline{OE}$	LE	D	Q
H	X	X	Z
L	L	X	$Q_n$
L	H	L	L
L	H	H	H

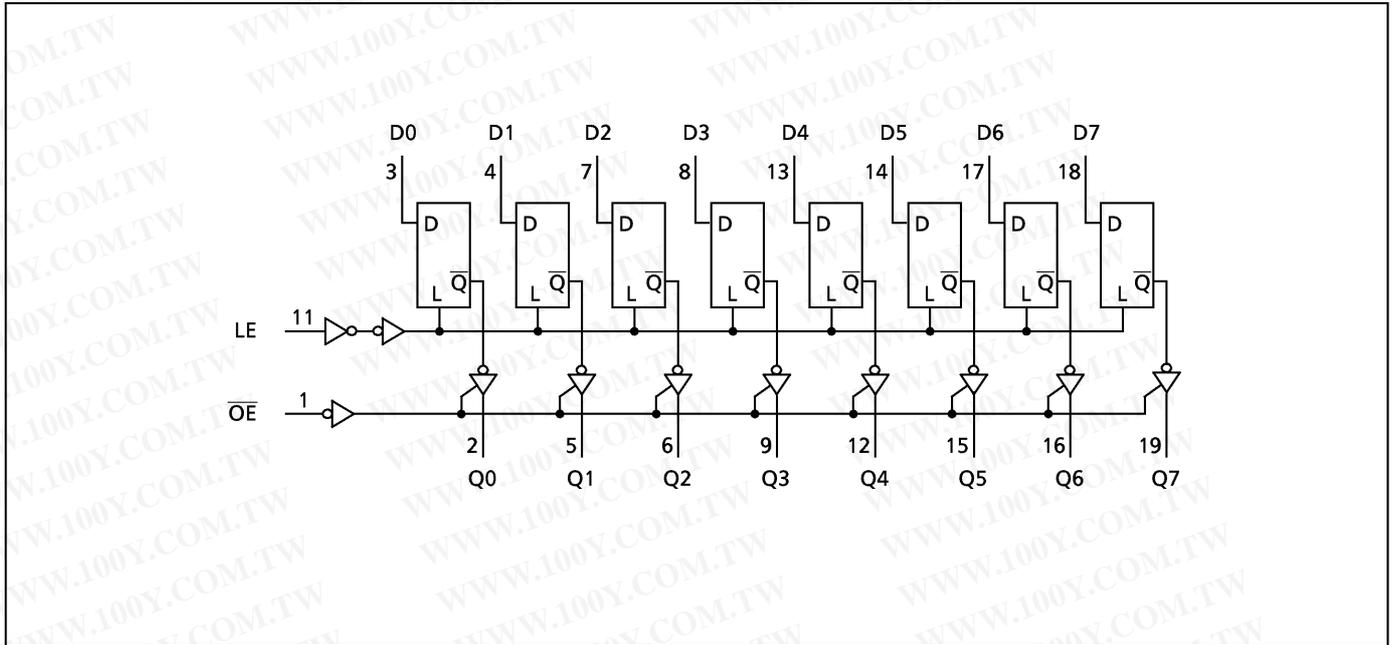
X : Don't Care  
 Z : High Impedance  
 $Q_n$  : Q outputs are latched at the time when the LE input is taken to a low logic level.

**IEC LOGIC SYMBOL**



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SYSTEM DIAGRAM



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**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V <sub>CC</sub>	-0.5~7	V
DC Input Voltage	V <sub>IN</sub>	-0.5~V <sub>CC</sub> +0.5	V
DC Output Voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> +0.5	V
Input Diode Current	I <sub>IK</sub>	± 20	mA
Output Diode Current	I <sub>OK</sub>	± 20	mA
DC Output Current	I <sub>OUT</sub>	± 35	mA
DC V <sub>CC</sub> /Ground Current	I <sub>CC</sub>	± 75	mA
Power Dissipation	P <sub>D</sub>	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T <sub>stg</sub>	-65~150	°C

\*500mW in the range of Ta = -40°C~65°C. From Ta = 65°C to 85°C a derating factor of -10mW/°C shall be applied until 300mW.

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**RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V <sub>CC</sub>	2~6	V
Input Voltage	V <sub>IN</sub>	0~V <sub>CC</sub>	V
Output Voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V
Operating Temperature	T <sub>opr</sub>	-40~85	°C
Input Rise and Fall Time	t <sub>r</sub> , t <sub>f</sub>	0~1000 (V <sub>CC</sub> = 2.0V) 0~500 (V <sub>CC</sub> = 4.5V) 0~400 (V <sub>CC</sub> = 6.0V)	ns

**DC ELECTRICAL CHARACTERISTICS**

PARAMETER	SYMBOL	TEST CONDITION	V <sub>CC</sub> (V)	Ta = 25°C			Ta = -40~85°C		UNIT	
				MIN.	TYP.	MAX.	MIN.	MAX.		
High - Level Input Voltage	V <sub>IH</sub>		2.0 4.5 6.0	1.50 3.15 4.20	— — —	— — —	1.50 3.15 4.20	— — —	V	
Low - Level Input Voltage	V <sub>IL</sub>		2.0 4.5 6.0	— — —	— — —	0.50 1.35 1.80	— — —	0.50 1.35 1.80	— — —	V
High - Level Output Voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -20μA	2.0	1.9	2.0	—	1.9	—	V
				4.5	4.4	4.5	—	4.4	—	
			I <sub>OH</sub> = -6 mA I <sub>OH</sub> = -7.8mA	4.5	4.18	4.31	—	4.13	—	V
				6.0	5.68	5.80	—	5.63	—	
Low - Level Output Voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20μA	2.0	—	0.0	0.1	—	0.1	V
				4.5	—	0.0	0.1	—	0.1	
			I <sub>OL</sub> = 6 mA I <sub>OL</sub> = 7.8mA	4.5	—	0.17	0.26	—	0.33	V
				6.0	—	0.18	0.26	—	0.33	
3 - State Output Off - State Current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND	6.0	—	—	± 0.5	—	± 5.0	μA	
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	6.0	—	—	± 0.1	—	± 1.0		
Quiescent Supply Current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	6.0	—	—	4.0	—	40.0		

**TIMING REQUIREMENTS (Input  $t_r = t_f = 6ns$ )**

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}(V)$	$T_a = 25^\circ C$		$T_a = -40-85^\circ C$	UNIT
				TYP.	LIMIT	LIMIT	
Minimum Pulse Width (LE)	$t_{w(H)}$		2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum Set-up Time (Dn)	$t_s$		2.0	—	50	65	
			4.5	—	10	13	
			6.0	—	9	11	
Minimum Hold Time (Dn)	$t_h$		2.0	—	5	5	
			4.5	—	5	5	
			6.0	—	5	5	

**AC ELECTRICAL CHARACTERISTICS (Input  $t_r = t_f = 6ns$ )**

PARAMETER	SYMBOL	TEST CONDITION	CL (pF)	$V_{CC}(V)$	$T_a = 25^\circ C$			$T_a = -40-85^\circ C$		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
Output Transition Time	$t_{TLH}$ $t_{THL}$		50	2.0	—	20	60	—	75	ns
				4.5	—	6	12	—	15	
				6.0	—	5	10	—	13	
Propagation Delay Time (LE-Q)	$t_{pLH}$		50	2.0	—	42	125	—	155	
				4.5	—	14	25	—	31	
				6.0	—	12	21	—	26	
	$t_{pHL}$		150	2.0	—	57	175	—	220	
				4.5	—	19	35	—	44	
				6.0	—	16	30	—	37	
Propagation Delay Time (D-Q)	$t_{pLH}$		50	2.0	—	42	125	—	155	
				4.5	—	14	25	—	31	
				6.0	—	12	21	—	26	
	$t_{pHL}$		150	2.0	—	57	175	—	220	
				4.5	—	19	35	—	44	
				6.0	—	16	30	—	37	
Output Enable Time	$t_{pZL}$	$R_L = 1k\Omega$	50	2.0	—	39	125	—	155	
				4.5	—	13	25	—	31	
				6.0	—	11	21	—	26	
	$t_{pZH}$		150	2.0	—	54	175	—	220	
				4.5	—	18	35	—	44	
				6.0	—	15	30	—	37	
Output Disable Time	$t_{pLZ}$ $t_{pHZ}$	$R_L = 1k\Omega$	50	2.0	—	30	125	—	155	
				4.5	—	14	25	—	31	
				6.0	—	13	21	—	26	
Input Capacitance	$C_{IN}$				—	5	10	—	10	pF
Output Capacitance	$C_{OUT}$				—	10	—	—	—	
Power Dissipation Capacitance	$C_{PD}(1)$				—	38	—	—	—	

Note (1)  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC}(opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 8 \text{ (per Latch)}$$

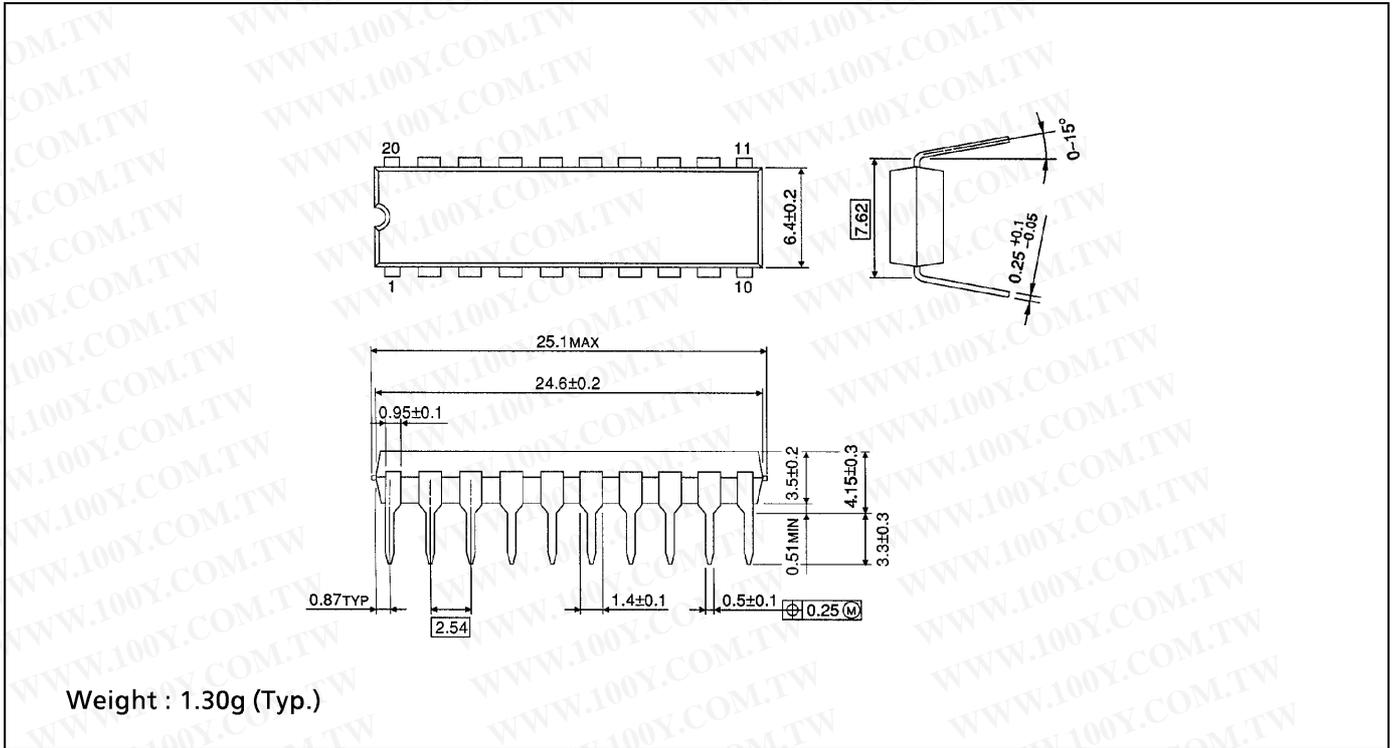
And the total  $C_{PD}$  when n pcs. of Latch operate can be gained by the following equation :

$$C_{PD}(\text{total}) = 22 + 16 \cdot n$$

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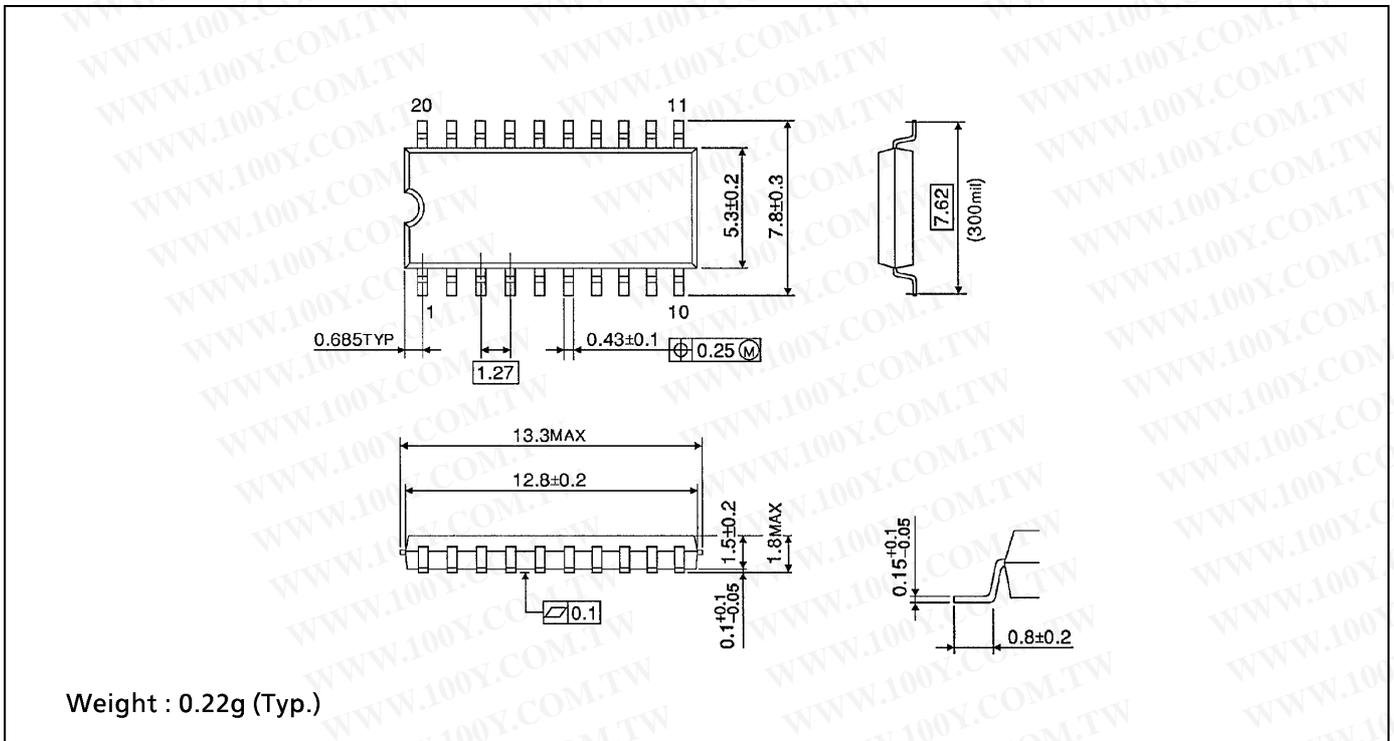
**DIP 20PIN PACKAGE DIMENSIONS (DIP20-P-300-2.54A)**

Unit in mm



**SOP 20PIN (200mil BODY) PACKAGE DIMENSIONS (SOP20-P-300-1.27)**

Unit in mm

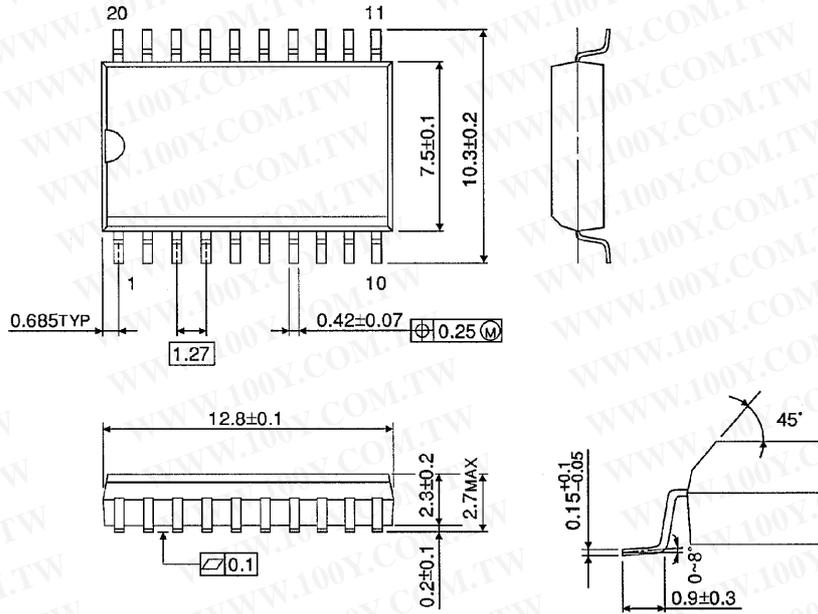


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**SOP 20PIN (300mil BODY) PACKAGE DIMENSIONS (SOL20-P-300-1.27)**

Unit in mm

(Note) This package is not available in Japan.



Weight : 0.46g (Typ.)

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